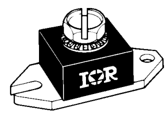
International
IOR Rectifier

129NQ...(R) SERIES

SCHOTTKY RECTIFIER

120 Amp


D-67

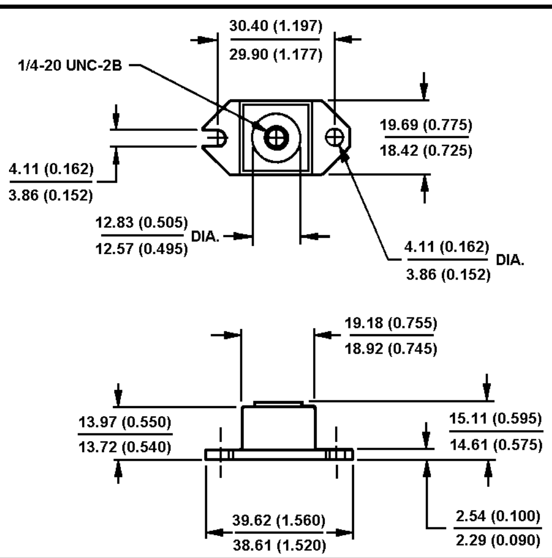
Major Ratings and Characteristics

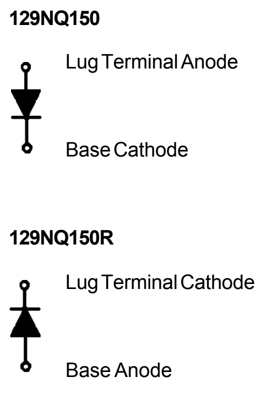
Characteristics		129NQ...(R)	Units
$I_{F(AV)}$	Rectangular waveform	120	A
V_{RRM}	range	135 to 150	V
I_{FSM}	@ tp = 5 μs sine	10000	A
V_F	@120Apk, T_J=125°C	0.74	V
T_J	range	-55 to 175	°C

Description/Features

The 129NQ... (R) high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175° C junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- 175° C T_J operation
- Unique high power, Half-Pak module
- Replaces two parallel DO-5's
- Easier to mount and lower profile than DO-5's
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability





Outline D-67 HALF PAK Module
Dimensions in millimeters and (inches)

Voltage Ratings

	Part number	129NQ135	129NQ150
V_R	Max. DC Reverse Voltage (V)	135	150
V_{RWM}	Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

	Parameters	129NQ	Units	Conditions	
$I_{F(AV)}$	Max. Average Forward Current * See Fig. 5	120	A	50% duty cycle @ T_C = 117° C, rectangular wave form	
I_{FSM}	Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	10000	A	5µs Sine or 3µs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied
		1200		10ms Sine or 6ms Rect. pulse	
E_{AS}	Non-Repetitive Avalanche Energy	15	mJ	T_J = 25 °C, I_{AS} = 1 Amps, L = 30 mH	
I_{AR}	Repetitive Avalanche Current	1	A	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A = 1.5 x V_R typical	

Electrical Specifications

	Parameters	129NQ	Units	Conditions	
V_{FM}	Max. Forward Voltage Drop (1) * See Fig. 1	1.07	V	@ 120A	T_J = 25 °C
		1.27	V	@ 240A	
		0.74	V	@ 120A	T_J = 125 °C
		0.86	V	@ 240A	
I_{RM}	Max. Reverse Leakage Current (1) * See Fig. 2	3	mA	T_J = 25 °C	V_R = rated V_R
		45	mA	T_J = 125 °C	
C_T	Max. Junction Capacitance	3000	pF	V_R = 5V_{DC}, (test signal range 100Khz to 1Mhz) 25 °C	
L_S	Typical Series Inductance	7.0	nH	From top of terminal hole to mounting plane	
dv/dt	Max. Voltage Rate of Change (Rated V_R)	10,000	V/ µs		

(1) Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters		129NQ	Units	Conditions
T_J	Max. Junction Temperature Range		-55 to 175	°C	
T_{stg}	Max. Storage Temperature Range		-55 to 175	°C	
R_{thJC}	Max. Thermal Resistance Junction to Case		0.40	°C/W	DC operation * See Fig. 4
R_{thCS}	Typical Thermal Resistance, Case to Heatsink		0.15	°C/W	Mounting surface, smooth and greased
wt	Approximate Weight		25.6 (0.9)	g (oz.)	
T	Mounting Torque	Min.	40 (35)	Kg-cm (Ibf-in)	Non-lubricated threads
		Max.	58 (50)		
	Terminal Torque	Min.	58 (50)		
		Max.	86 (75)		
	Case Style		HALF PAK Module		

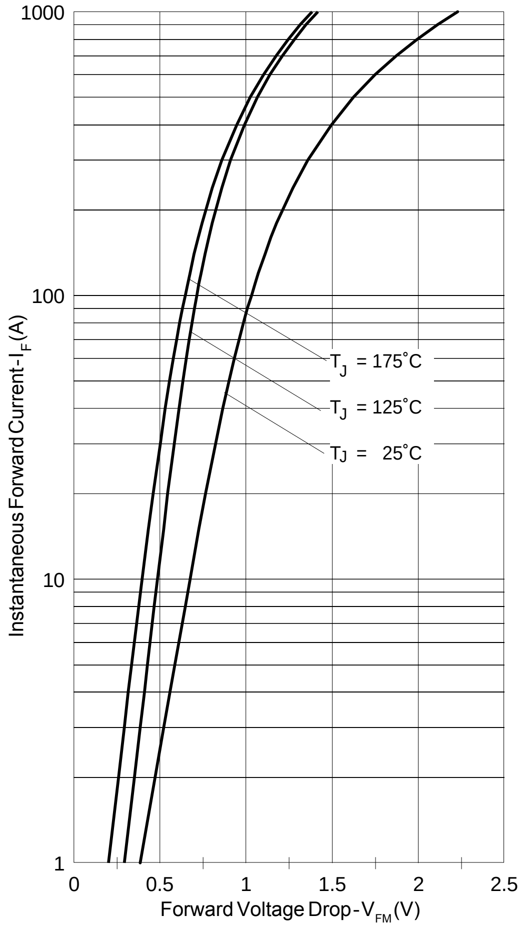


Fig. 1 - Max. Forward Voltage Drop Characteristics

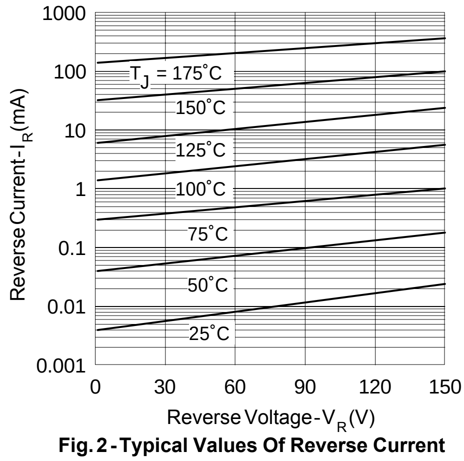


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

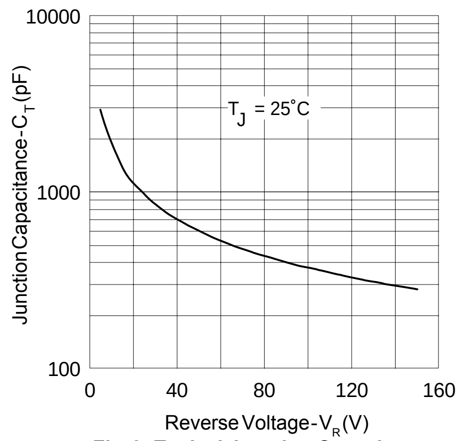


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

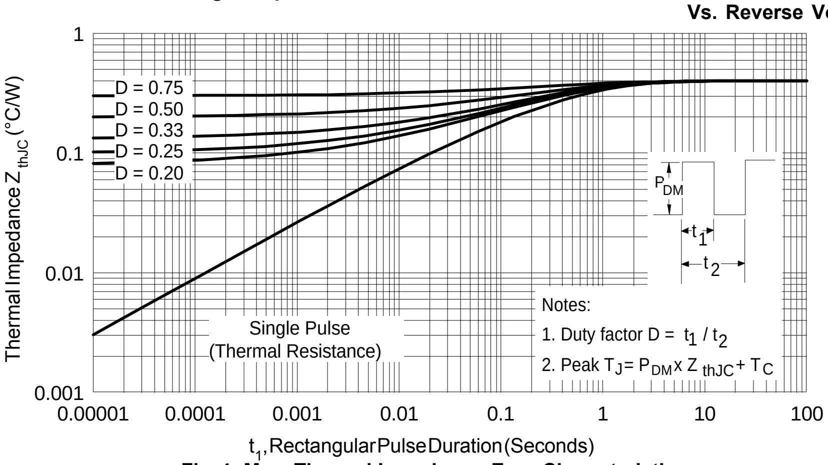


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

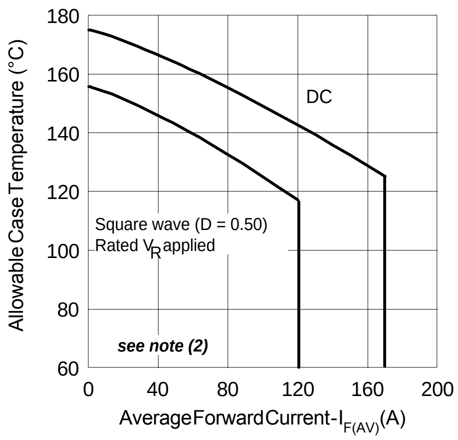


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

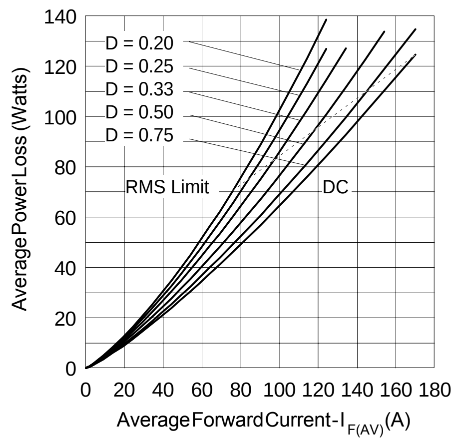


Fig. 6 - Forward Power Loss Characteristics

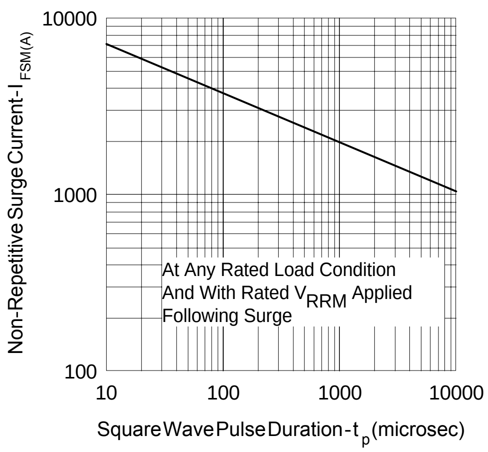


Fig. 7 - Max. Non-Repetitive Surge Current

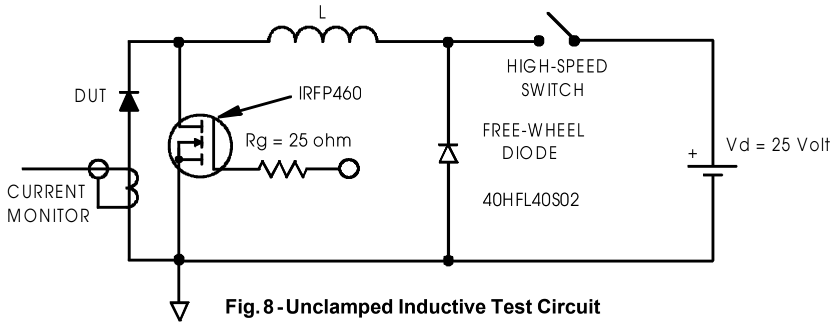


Fig. 8 - Unclamped Inductive Test Circuit

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM}$ @ $(I_{F(AV)} / D)$ (see Fig. 6);
Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; I_R @ V_{R1} = rated V_R